National Semiconductor

54ABT/74ABT573C
Octal D-Type Latch with TRI-STATE® Outputs

General Description

The 'ABT573C is an octal latch with buffered common Latch Enable (LE) and buffered common Output Enable ($\overline{OE}$) inputs.

This device is functionally identical to the 'ABT373C but has different pinouts.

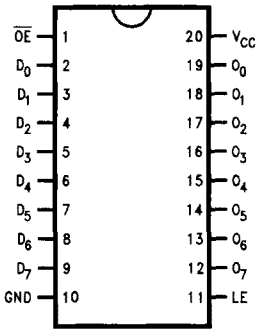
Features

- Inputs and outputs on opposite sides of package allow easy interface with microprocessors
- Useful as input or output port for microprocessors
- Functionally identical to 'ABT373C
- TRI-STATE outputs for bus interfacing
- Output sink capability of 64 mA, source capability of 32 mA
- Guaranteed output skew
- Guaranteed multiple output switching specifications
- Output switching specified for both 50 pF and 250 pF loads
- Guaranteed simultaneous switching, noise level and dynamic threshold performance
- Guaranteed latchup protection
- High impedance glitch-free bus loading during entire power up and power down
- Nondestructive hot insertion capability

Ordering Code: See Section 10

Connection Diagrams

Pin Assignment for DIP, SOIC, SSOP and Flatpak



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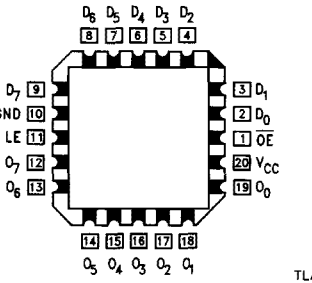
Pin Assignment for LCC



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Pin Names	Description
D_0–D_7	Data Inputs
LE	Latch Enable Input (Active HIGH)
$\overline{OE}$	TRI-STATE Output Enable Input (Active LOW)
O_0–O_7	TRI-STATE Latch Outputs

Functional Description

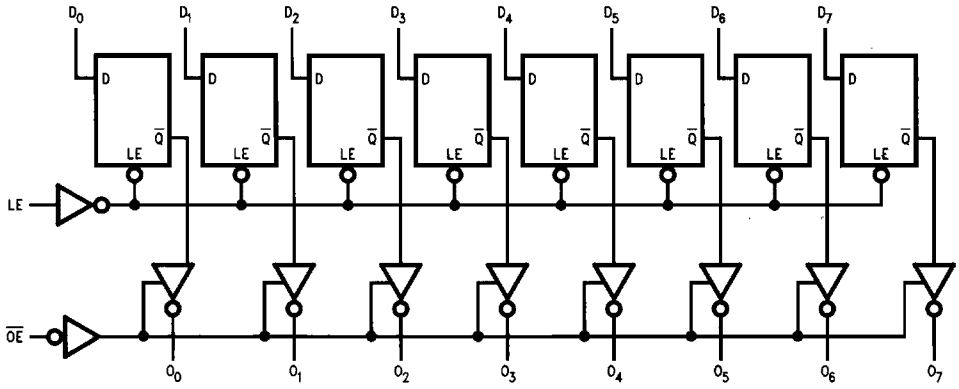
The 'ABT573C contains eight D-type latches with TRI-STATE output buffers. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW the latches store the information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE. The TRI-STATE buffers are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the buffers are in the bi-state mode. When $\overline{OE}$ is HIGH the buffers are in the high impedance mode but this does not interfere with entering new data into the latches.

Function Table

Inputs			Outputs
$\overline{OE}$	LE	D	O
L	H	H	H
L	H	L	L
L	L	X	O_0
H	X	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
O_0 = Value stored from previous clock cycle

Logic Diagram



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Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	
Ceramic	−55°C to +175°C
Plastic	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output in the Disabled or Power-Off State	−0.5V to +5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output in LOW State (Max)	Twice the rated I_{OL} (mA)
DC Latchup Source Current	−500 mA
Over Voltage Latchup (I/O)	10V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

Free Air Ambient Temperature	
Military	−55°C to +125°C
Commercial	−40°C to +85°C
Supply Voltage	
Military	+4.5V to +5.5V
Commercial	+4.5V to +5.5V
Minimum Input Edge Rate	(ΔV/Δt)
Data Input	50 mV/ns
Enable Input	20 mV/ns

DC Electrical Characteristics

Symbol	Parameter		ABT573C Min	ABT573C Typ	ABT573C Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	54ABT/74ABT	2.5			V	Min	I_{OH} = −3 mA
		54ABT	2.0					I_{OH} = −24 mA
		74ABT	2.0					I_{OH} = −32 mA
V_{OL}	Output LOW Voltage	54ABT			0.55	V	Min	I_{OL} = 48 mA
		74ABT			0.55			I_{OL} = 64 mA
I_{IH}	Input HIGH Current				5	μA	Max	V_{IN} = 2.7V (Note 2)
					5			V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test				7	μA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−5	μA	Max	V_{IN} = 0.5V (Note 2)
					−5			V_{IN} = 0.0V
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 μA All Other Pins Grounded
I_{OZH}	Output Leakage Current				50	μA	0 − 5.5V	V_{OUT} = 2.7V; $\overline{OE}$ = 2.0V
I_{OZL}	Output Leakage Current				−50	μA	0 − 5.5V	V_{OUT} = 0.5V; $\overline{OE}$ = 2.0V
I_{OS}	Output Short-Circuit Current		−100		−275	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output High Leakage Current				50	μA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test				100	μA	0.0	V_{OUT} = 5.5V; All Others GND
I_{CCH}	Power Supply Current				50	μA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current				30	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current				50	μA	Max	$\overline{OE}$ = V_{CC} All Others at V_{CC} or GND
I_{CCT}	Additional I_{CC}/Input	Outputs Enabled			2.5	mA	Max	V_I = V_{CC} − 2.1V
		Outputs TRI-STATE			2.5	mA		Enable Input V_I = V_{CC} − 2.1V
		Outputs TRI-STATE			2.5	mA		Data Input V_I = V_{CC} − 2.1V All Others at V_{CC} or GND
I_{CCD}	Dynamic I_{CC} (Note 2)	No Load			0.12	mA/ MHz	Max	Outputs Open $\overline{OE}$ = GND, LE = V_{CC} (Note 1) One Bit Toggling, 50% Duty Cycle

Note 1: For 8 bits toggling, I_{CCD} < 0.8 mA/MHz.

Note 2: Guaranteed but not tested.

DC Electrical Characteristics (SOIC package) (Continued)

Symbol	Parameter	Min	Typ	Max	Units	V_{CC}	Conditions C_L = 50 pF, R_L = 500Ω
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}		0.7	1.0	V	5.0	T_A = 25°C (Note 1)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	−1.5	−1.2		V	5.0	T_A = 25°C (Note 1)
V_{OHV}	Minimum High Level Dynamic Output Voltage	2.5	3.0		V	5.0	T_A = 25°C (Note 3)
V_{IHD}	Minimum High Level Dynamic Input Voltage	2.2	1.8		V	5.0	T_A = 25°C (Note 2)
V_{ILD}	Maximum Low Level Dynamic Input Voltage		1.0	0.7	V	5.0	T_A = 25°C (Note 2)

Note 1: Max number of outputs defined as (n). n − 1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.

Note 2: Max number of data inputs (n) switching. n − 1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). Guaranteed, but not tested.

Note 3: Max number of outputs defined as (n). n − 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.

AC Electrical Characteristics: See Section 2 for Waveforms (SOIC and SSOP package)

Symbol	Parameter	74ABTC T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			54ABTC T_A = −55°C to +125°C, V_{CC} = 4.5V to 5.5V, C_L = 50 pF		74ABTC T_A = −40°C to +85°C, V_{CC} = 4.5V to 5.5V, C_L = 50 pF		Units	Fig. No.
		Min	Typ	Max	Min	Max	Min	Max		
t_{PLH} t_{PHL}	Propagation Delay D_n to O_n	1.5 1.5	2.7 2.8	4.5 4.5			1.5 1.5	4.5 4.5	ns	2-3, 5
t_{PLH} t_{PHL}	Propagation Delay LE to O_n	1.5 1.5	3.1 3.0	5.0 5.0			1.5 1.5	5.0 5.0	ns	2-3, 5
t_{PZH} t_{PZL}	Output Enable Time	1.5 1.5	3.1 3.1	5.3 5.3			1.5 1.5	5.3 5.3	ns	2-4
t_{PHZ} t_{PLZ}	Output Disable Time Time	1.0 1.0	3.6 3.4	5.4 5.4			1.0 1.0	5.4 5.4	ns	2-4

AC Operating Requirements: See Section 2 for Waveforms (SOIC and SSOP packages)

Symbol	Parameter	74ABTC T_A = +25°C, V_{CC} = +5.0V, C_L = 50 pF			54ABTC T_A = −55°C to +125°C, V_{CC} = 4.5V to 5.5V, C_L = 50 pF		74ABTC T_A = −40°C to +85°C, V_{CC} = 4.5V to 5.5V, C_L = 50 pF		Units	Fig. No.
		Min	Typ	Max	Min	Max	Min	Max		
f_{toggle}	Max Toggle Frequency		100						MHz	
$t_s(H)$ $t_s(L)$	Set Time, HIGH or LOW D_n to LE	1.5 1.5					1.5 1.5		ns	2-6
$t_h(H)$ $t_h(L)$	Hold Time, HIGH or LOW D_n to LE	1.0 1.0					1.0 1.0		ns	2-6
$t_w(H)$	Pulse Width, LE HIGH	3.0					3.0		ns	2-3

Extended AC Electrical Characteristics: See Section 2 for Waveforms (SOIC package)

Symbol	Parameter	74ABTC $T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 50$ pF, 8 Outputs Switching (Note 4)		74ABTC $T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 250$ pF (Note 5)		74ABTC $T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 250$ pF, 8 Outputs Switching (Note 6)		Units	Fig. No.
		Min	Max	Min	Max	Min	Max		
t_{PLH} t_{PHL}	Propagation Delay D_n to O_n	1.5 1.5	5.2 5.2	2.0 2.0	6.8 6.8	2.0 2.0	9.0 9.0	ns	2-3, 5
t_{PLH} t_{PHL}	Propagation Delay LE to O_n	1.5 1.5	5.5 5.5	2.0 2.0	7.5 7.5	2.0 2.0	9.5 9.5	ns	2-3, 5
t_{PZH} t_{PZL}	Output Enable Time	1.5 1.5	6.2 6.2	2.0 2.0	8.0 8.0	2.0 2.0	10.5 10.5	ns	2-4
t_{PHZ} t_{PLZ}	Output Disable Time	1.0 1.0	5.5 5.5	(Note 7)		(Note 7)		ns	2-4

Note 4: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 5: This specification is guaranteed but not tested. The limits represent propagation delay with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 6: This specification is guaranteed but not tested. The limits represent propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.) with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 7: The TRI-STATE delay times are dominated by the RC network (500Ω, 250 pF) on the output and has been excluded from the datasheet.

Skew: See Section 2 (SOIC package) (Note 3)

Symbol	Parameter	74ABTC $T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 50$ pF, 8 Outputs Switching (Note 3)	74ABTC $T_A = -40°C$ to $+85°C$, $V_{CC} = 4.5V$ to $5.5V$, $C_L = 250$ pF, 8 Outputs Switching (Note 4)	Units	Fig. No.
		Max	Max		
t_{OSHL} (Note 1)	Pin to Pin Skew HL Transitions	1.0	1.5	ns	2-13
t_{OSLH} (Note 1)	Pin to Pin Skew LH Transitions	1.0	1.5	ns	2-13
t_{PS} (Note 5)	Duty Cycle LH–HL Skew	1.4	3.5	ns	2-14
t_{OST} (Note 1)	Pin to Pin Skew LH/HL Transitions	1.5	3.9	ns	2-17
t_{PV} (Note 2)	Device to Device Skew LH/HL Transitions	2.0	4.0	ns	2-20

Note 1: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH to LOW (t_{OSHL}), LOW to HIGH (t_{OSLH}), or any combination switching LOW to HIGH and/or HIGH to LOW (t_{OST}). This specification is guaranteed but not tested.

Note 2: Propagation delay variation for a given set of conditions (i.e., temperature and V_{CC}) from device to device. This specification is guaranteed but not tested.

Note 3: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.)

Note 4: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

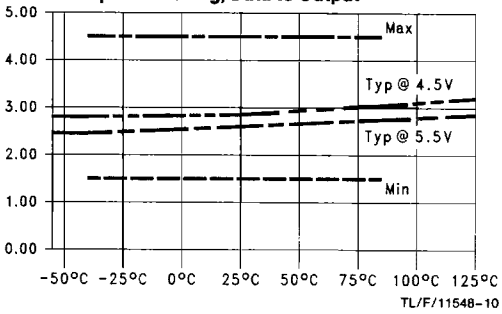
Note 5: This describes the difference between the delay of the LOW-to-HIGH and the HIGH-to-LOW transition on the same pin. It is measured across all the outputs (drivers) on the same chip, the worst (largest delta) number is the guaranteed specification. This specification is guaranteed but not tested.

Capacitance

Symbol	Parameter	Typ	Units	Conditions (T_A = 25°C)
C_{IN}	Input Capacitance	5	pF	V_{CC} = 0V
C_{OUT} (Note 1)	Output Capacitance	9	pF	V_{CC} = 5.0V

Note 1: C_{OUT} is measured at frequency f = 1 MHz per MIL-STD-883B, Method 3012.

T_{PLH} vs Temperature (T_A), C_L = 50 pF, 1 Output Switching, Data to Output



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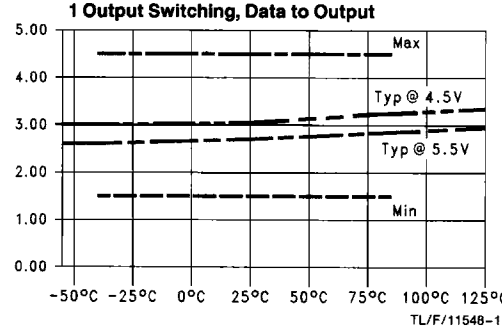
T_{PHL} vs Temperature (T_A), C_L = 50 pF, 1 Output Switching, Data to Output



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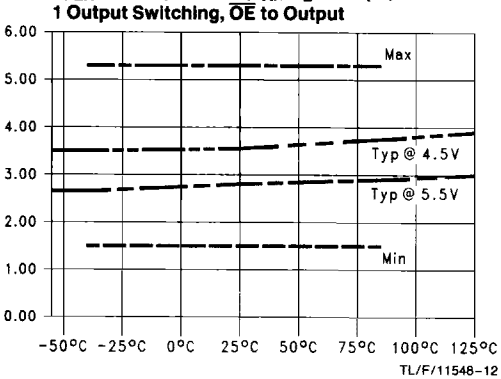
T_{PZH} vs Temperature (T_A), C_L = 50 pF, 1 Output Switching, $\overline{OE}$ to Output



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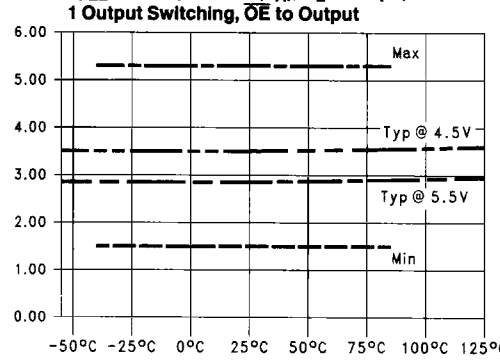
T_{PZL} vs Temperature (T_A), C_L = 50 pF, 1 Output Switching, $\overline{OE}$ to Output



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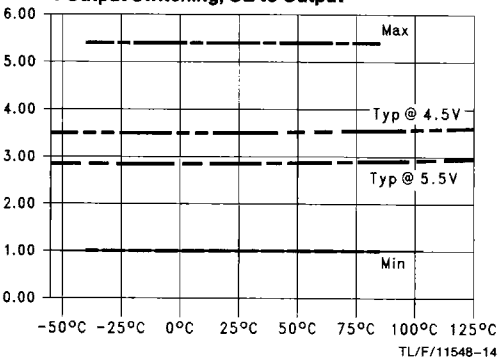
T_{PHZ} vs Temperature (T_A), C_L = 50 pF, 1 Output Switching, $\overline{OE}$ to Output



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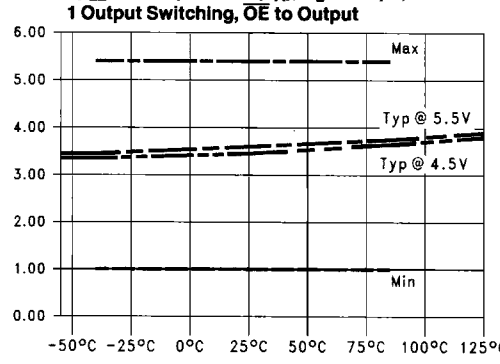
T_{PLZ} vs Temperature (T_A), C_L = 50 pF, 1 Output Switching, $\overline{OE}$ to Output



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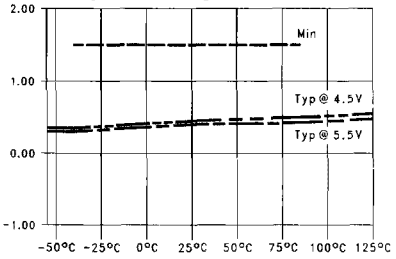
Dashed lines represent design characteristics; for specified guarantees, refer to AC Characteristics Tables.

T_{SET} LOW vs Temperature (T_A), C_L = 50 pF, 1 Output Switching, Data to LE



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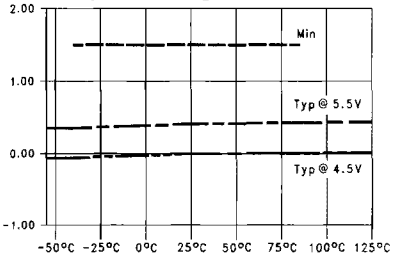
T_{SET} HIGH vs Temperature (T_A), C_L = 50 pF, 1 Output Switching, Data to LE



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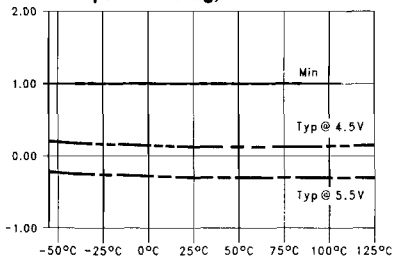
T_{HOLD} HIGH vs Temperature (T_A), C_L = 50 pF, 1 Output Switching, Data to LE



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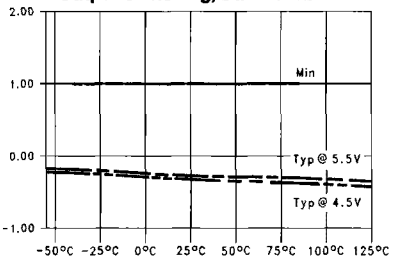
T_{HOLD} LOW vs Temperature (T_A), C_L = 50 pF, 1 Output Switching, Data to LE



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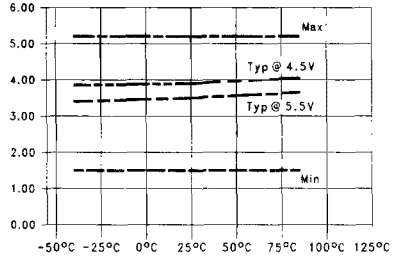
T_{PLH} vs Temperature (T_A), C_L = 50 pF, 8 Outputs Switching, Data to Output



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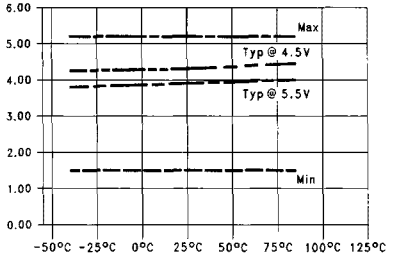
T_{PHL} vs Temperature (T_A), C_L = 50 pF, 8 Outputs Switching, Data to Output



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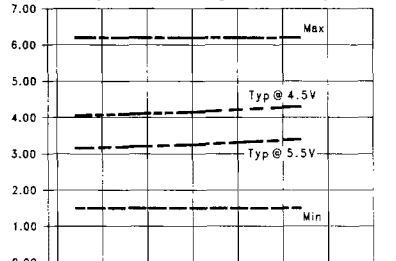
T_{PZH} vs Temperature (T_A), C_L = 50 pF, 8 Outputs Switching, $\overline{OE}$ to Output



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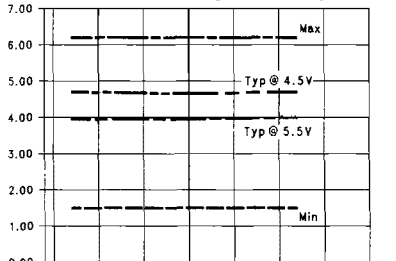
T_{PZL} vs Temperature (T_A), C_L = 50 pF, 8 Outputs Switching, $\overline{OE}$ to Output



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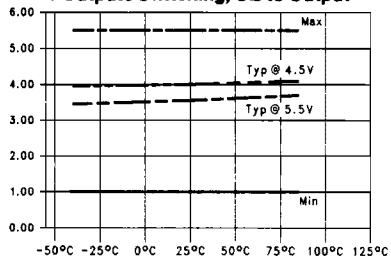
Dashed lines represent design characteristics; for specified guarantees, refer to AC Characteristics Tables.

T_{PHZ} vs Temperature (T_A), C_L = 50 pF, 8 Outputs Switching, $\overline{OE}$ to Output



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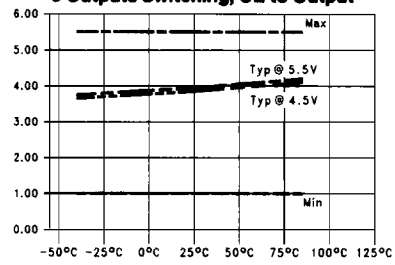
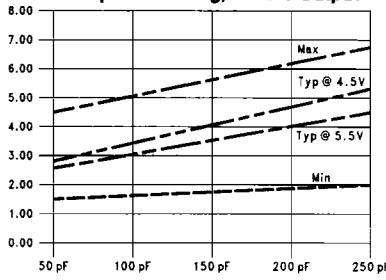
T_{PLZ} vs Temperature (T_A), C_L = 50 pF, 8 Outputs Switching, $\overline{OE}$ to Output



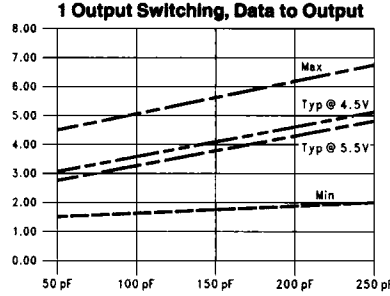
TL/F/11548-25

T_{PLH} vs Load Capacitance T_A = 25°C, 1 Output Switching, Data to Output



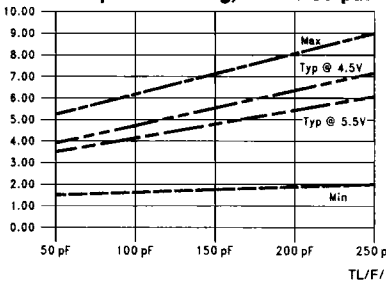
TL/F/11548-26

T_{PHL} vs Load Capacitance T_A = 25°C, 1 Output Switching, Data to Output



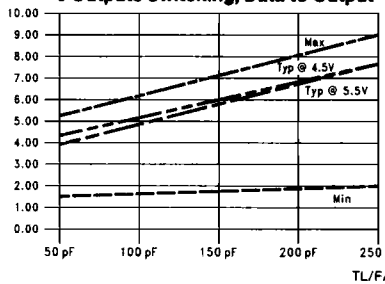
TL/F/11548-27

T_{PLH} vs Load Capacitance T_A = 25°C, 8 Outputs Switching, Data to Output



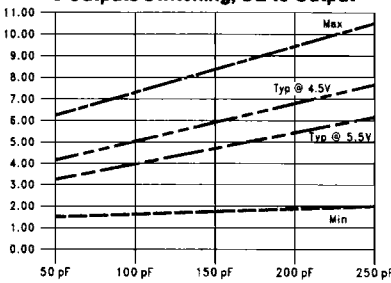
TL/F/11548-28

T_{PHL} vs Load Capacitance T_A = 25°C, 8 Outputs Switching, Data to Output



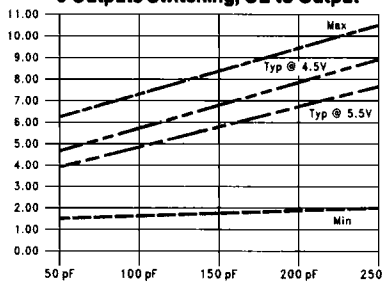
TL/F/11548-29

T_{PZH} vs Load Capacitance T_A = 25°C, 8 Outputs Switching, $\overline{OE}$ to Output



TL/F/11548-30

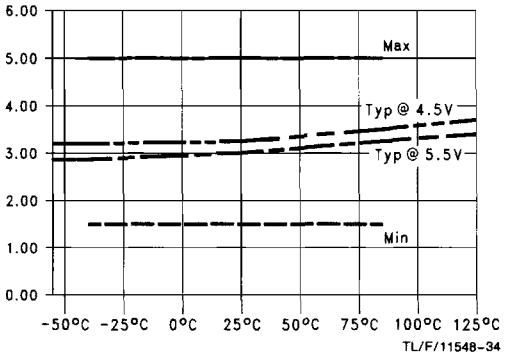
T_{PZL} vs Load Capacitance T_A = 25°C, 8 Outputs Switching, $\overline{OE}$ to Output



TL/F/11548-31

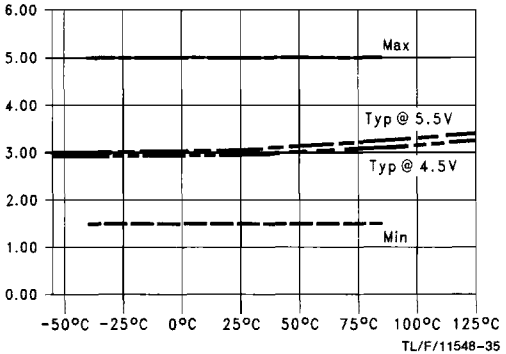
Dashed lines represent design characteristics; for specified guarantees, refer to AC Characteristics Tables.

T_{PLH} vs Temperature (T_A), C_L = 50 pF, 1 Output Switching, LE to Output



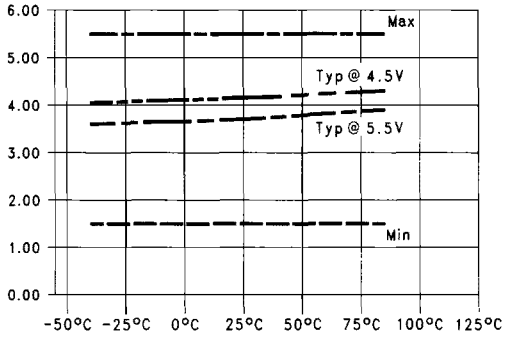
TL/F/11548–34

T_{PHL} vs Temperature (T_A), C_L = 50 pF, 1 Output Switching, LE to Output



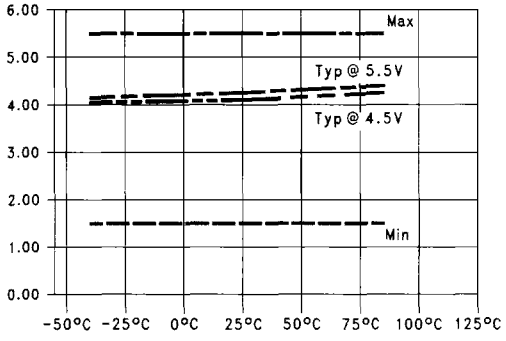
TL/F/11548–35

T_{PLH} vs Temperature (T_A), C_L = 50 pF, 8 Outputs Switching, LE to Output



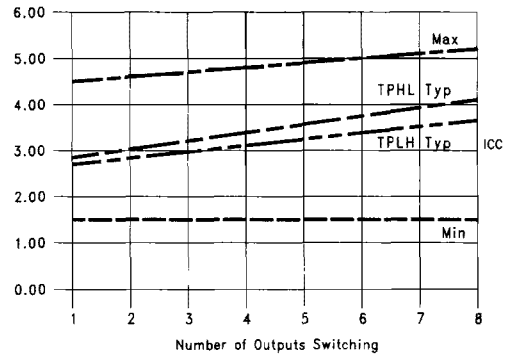
TL/F/11548–36

T_{PHL} vs Temperature (T_A), C_L = 50 pF, 8 Outputs Switching, LE to Output



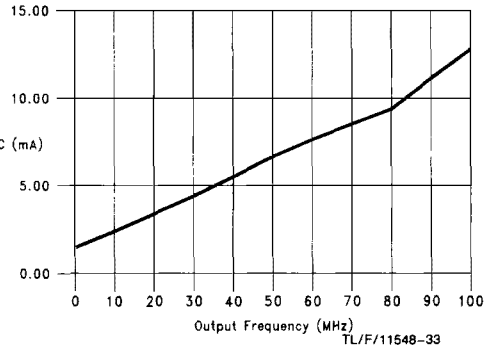
TL/F/11548–37

T_{PLH} and T_{PHL} vs Number Outputs Switching, C_L = 50 pF, T_A = 25°C, V_{CC} = 5.0V, Outputs In Phase Data to Output



TL/F/11548–32

Typical I_{CC} vs Output Switching Frequency, C_L = 0 pF, V_{CC} = V_{IH} = 5.5V, LE = GND, 1 Output Switching at 50% Duty Cycle, Data to Output, Transparent Mode with Unused Data Inputs = V_{IH}



TL/F/11548–33

Dashed lines represent design characteristics; for specified guarantees, refer to AC Characteristics Tables.